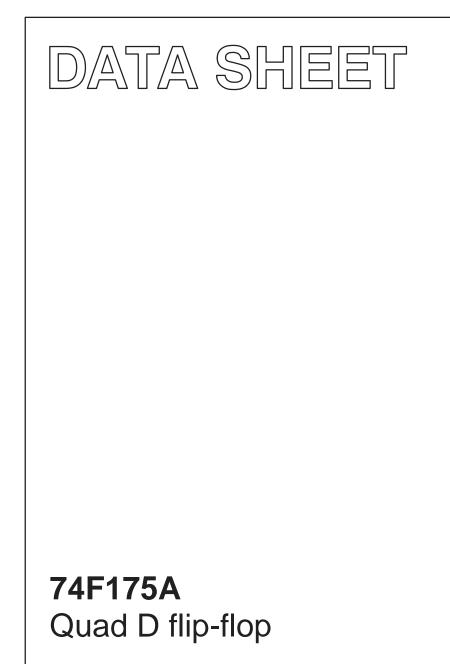
# INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Mar 12 IC15 Data Handbook 2000 Jun 30



Philips Semiconductors

# 74F175A

### **FEATURES**

- Four edge-triggered D-type flip-flops
- Buffered common clock
- Buffered asynchronous Master Reset
- True and complementary outputs
- Industrial temperature range available (-40°C to +85°C)
- PNP light loading inputs

### DESCRIPTION

The 74F175A is a quad, edge-triggered D-type flip-flop with individual D inputs and both Q and  $\overline{Q}$  outputs. The common buffered Clock (CP) and Master Reset (MR) inputs load and reset (clear) all flip-flops simultaneously.

The register is fully edge-triggered. The state of each D input, one setup time before the Low-to-High clock transition is transferred to the corresponding flip-flop's Q output.

All Q outputs will be forced Low independently of clock or data inputs by a Low voltage level on the MR input. The device is useful for applications where both true and complementary outputs are required, and the CP and MR are common to all storage elements.

		_							
MR 1		16 V <sub>CC</sub>							
Q0 2		15 Q3							
Q0 3		14 Q3							
D0 4		13 D3							
D1 5		12 D2							
Q1 6		11 Q2							
Q1 7		10 Q2							
GND 8		9 CP							
	L	1							
	Sł	-00718							

**PIN CONFIGURATION** 

TYPE	TYPICAL f <sub>max</sub>	TYPICAL SUPPLY CURRENT (TOTAL)
74F175A	160MHz	22mA

### **ORDERING INFORMATION**

	ORDER CODE		
DESCRIPTION	COMMERCIAL RANGE V <sub>CC</sub> = 5V ±10%, T <sub>amb</sub> = 0°C to +70°C	INDUSTRIAL RANGE $V_{CC} = 5V \pm 10\%$ , $T_{amb} = -40^{\circ}C$ to +85°C	PKG. DWG. #
16-pin plastic DIP	N74F175AN	I74F175AN	SOT38-4
16-pin plastic SO	N74F175AD	I74F175AD	SOT109-1

### INPUT AND OUTPUT LOADING AND FAN OUT TABLE

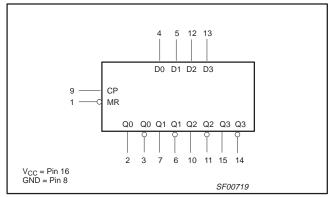
PINS	DESCRIPTION	DESCRIPTION					
D0 – D3	Data inputs	74F175A	1.0/0.033	20μΑ/20μΑ			
MR	Master reset input (active-Low)	74F175A	1.0/0.033	20μΑ/20μΑ			
CP	Clock input (active rising edge)	74F175A	1.0/0.033	20μΑ/20μΑ			
Q0–Q3	True outputs		50/33	1.0mA/20mA			
<u>Q</u> 0– <u>Q</u> 3	Complementary outputs		50/33	1.0mA/20mA			

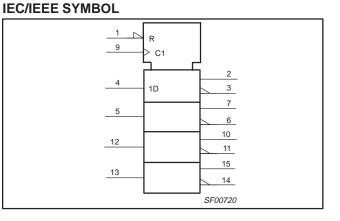
NOTE:

One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

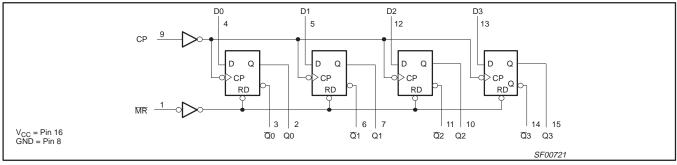
## 74F175A

## LOGIC SYMBOL





### LOGIC DIAGRAM



### **FUNCTION TABLE**

	INPUTS		OUTF	PUTS	OPERATING MODE		
MR	СР	Dn	Q <sub>n</sub>	<u>Q</u> n			
L	Х	Х	L	Н	Reset (clear)		
Н	$\uparrow$	h	Н	L	Load "1"		
Н	$\uparrow$	I	L	Н	Load "0"		

- H = High voltage level h = High state must be present one setup time before the Low-to-High clock transition
- Low voltage level L = L
  - Low state must be present one setup time before the = Low-to-High clock transition
- = Don't care
- X ↑ Low-to-High clock transition =

## **ABSOLUTE MAXIMUM RATINGS**

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V <sub>CC</sub>	Supply voltage		-0.5 to +7.0	V
V <sub>IN</sub>	Input voltage		-0.5 to +7.0	V
I <sub>IN</sub>	Input current		-30 to +5	mA
V <sub>OUT</sub>	Voltage applied to output in High output state	–0.5 to $V_{CC}$	V	
I <sub>OUT</sub>	Current applied to output in Low output state		40	mA
	Operating free air temperature repar	Commercial range	0 to +70	°C
T <sub>amb</sub>	Operating free air temperature range	Industrial range	-40 to +85	°C
T <sub>stg</sub>	Storage temperature range	-65 to +150	°C	

74F175A

## **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER			LIMITS		UNIT
			MIN	NOM	MAX	1
V <sub>CC</sub>	Supply voltage		4.5	5.0	5.5	V
V <sub>IH</sub>	High-level input voltage	2.0			V	
VIL	Low-level input voltage			0.8	V	
I <sub>IK</sub>	Input clamp current				-18	mA
I <sub>OH</sub>	High-level output current				-1	mA
I <sub>OL</sub>	Low-level output current				20	mA
т		Commercial range	0		+70	°C
T <sub>amb</sub>	Operating free air temperature range	Industrial range	-40		+85	°C

## **DC ELECTRICAL CHARACTERISTICS**

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER	TEST			LIMITS			
		CONDITION	MIN	TYP <sup>2</sup>	MAX			
V <sub>OH</sub>	High-level output voltage	$V_{CC}$ = MIN, $V_{IL}$ = MAX, $V_{IH}$ = MIN, $I_{OH}$ = MAX	$\pm 10\% V_{CC}$	2.5			v	
VОН	righ-level output voltage	$V_{IH} = MIN, I_{OH} = MAX$	$\pm 5\%V_{CC}$	2.7	3.4		v	
V <sub>OL</sub>	Low-level output voltage	$V_{CC} = MIN, V_{IL} = MAX,$ $V_{IH} = MIN, I_{OL} = MAX$	$\pm 10\% V_{CC}$		0.30	0.5	v	
		$V_{IH} = MIN, I_{OL} = MAX$	$\pm 5\%V_{CC}$		0.30	0.5	v	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = MIN, I_I = I_{IK}$	•		-0.73	-1.2	V	
lj	Input current at maximum input voltage	$V_{CC} = 0.0V, V_{I} = 7.0V$				100	μΑ	
Ι <sub>ΙΗ</sub>	High-level input current	$V_{CC} = MAX, V_I = 2.7V$				20	μA	
IIL	Low-level input current	$V_{CC} = MAX, V_I = 0.5V$	$V_{CC} = MAX, V_I = 0.5V$			-20	μΑ	
I <sub>OS</sub>	Short-circuit output current <sup>3</sup>	V <sub>CC</sub> = MAX	-60		-150	mA		
Icc	Supply current (total)	V <sub>CC</sub> = MAX		22	31	mA		

Notes to DC electrical characteristics

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

 All typical values are at V<sub>CC</sub> = 5V, T<sub>amb</sub> = 25°C.
Not more than one output should be shorted at a time. For testing I<sub>OS</sub>, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

## **AC ELECTRICAL CHARACTERISTICS**

							NITS	_		
			Ta	<sub>mb</sub> = 25°	С	$T_{amb} = 0^{\circ}C$	C to +70°C	$T_{amb} = -40$		
SYMBOL	PARAMETER	TEST CONDITION		V <sub>CC</sub> = +5V C <sub>L</sub> = 50pF,		V <sub>CC</sub> = +5. C <sub>1</sub> = 5		V <sub>CC</sub> = +5. C <sub>1</sub> = 5	UNIT	
			$R_L = 500\Omega$		$R_L =$		$R_L = 500\Omega$			
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>	Maximum clock frequency	Waveform 1	140	160		125		110		MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay CP to Qn or Qn	Waveform 1	3.0 4.5	4.0 6.0	6.5 8.5	2.5 4.0	7.5 9.0	2.5 4.0	8.0 10.0	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay MR to Qn	Waveform 3	4.5	6.5	9.0	4.5	10.0	4.5	11.0	ns
t <sub>PHL</sub> t <sub>PHL</sub>	Propagation delay $\overline{MR}$ to $\overline{Q}n$	Waveform 3	4.5	6.0	8.0	4.0	9.0	4.0	10.0	ns

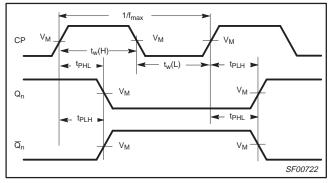
## 74F175A

### AC SETUP REQUIREMENTS

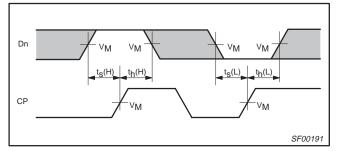
						LIN	NITS			
			Ta	$_{\rm imb}$ = 25 $^{\circ}$	С	$T_{amb} = 0^{\circ}C$	C to +70°C	$T_{amb} = -40$	°C to +85°C	1
SYMBOL	PARAMETER	TEST		/ <sub>CC</sub> = +5\		V <sub>CC</sub> = +5.		V <sub>CC</sub> = +5.		UNIT
		CONDITION	C <sub>L</sub> = 50pF, R <sub>L</sub> = 500Ω		C <sub>L</sub> = 5 R <sub>L</sub> =		C <sub>L</sub> = 50pF, R <sub>L</sub> = 500Ω			
			MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	
t <sub>s</sub> (H) t <sub>s</sub> (L)	Setup time, High or Low Dn to CP	Waveform 2	3.0 3.0			3.5 3.5		4.0 4.0		ns
t <sub>h</sub> (H) t <sub>h</sub> (L)	Hold time, High or Low Dn to CP	Waveform 2	0.0 0.0			0.0 0.0		0.0 0.0		ns
t <sub>w</sub> (H) t <sub>w</sub> (L)	CP Pulse width High or Low	Waveform 1	3.0 4.0			3.5 5.0		4.0 5.5		ns
t <sub>w</sub> (L)	MR Pulse width Low	Waveform 3	3.5			3.5		4.0		ns
t <sub>REC</sub>	Recovery time MR to CP	Waveform 3	4.0			4.5		5.0		ns

## AC WAVEFORMS

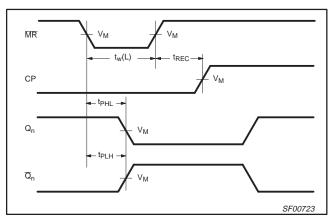
For all waveforms,  $V_M = 1.3V$ .



Waveform 1. Propagation delay for clock input to output, clock pulse width, and maximum clock frequency



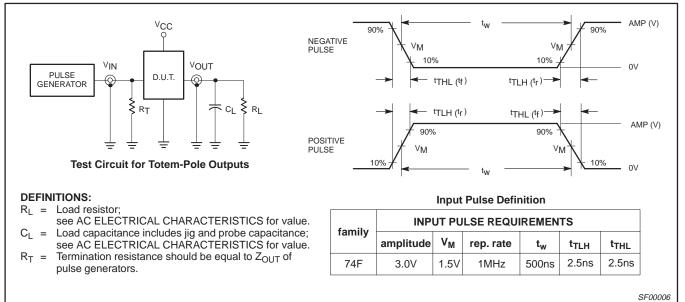
Waveform 2. Data setup time and hold times



Waveform 3. Master Reset pulse width, Master Reset to output delay and Master Reset to Clock recovery time

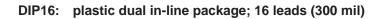
## 74F175A

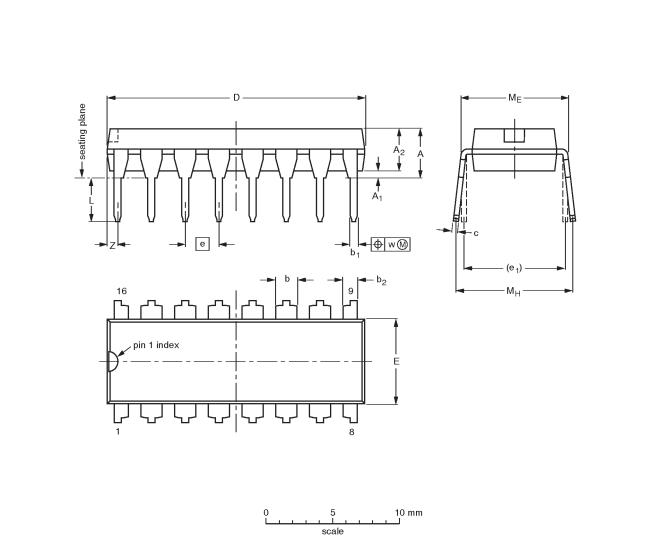
### **TEST CIRCUIT AND WAVEFORMS**



74F175A

## Product specification





### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

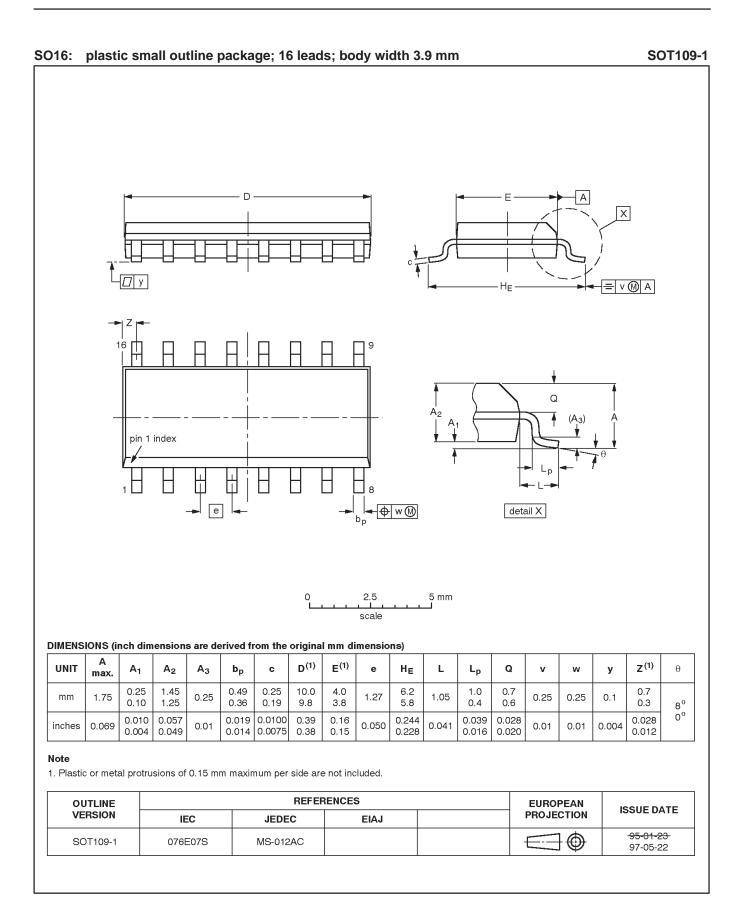
#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT38-4					<del>-92-11-17</del> 95-01-14	

74F175A

Product specification



74F175A

NOTES

# 74F175A

### Data sheet status

Data sheet status	Product status	Definition <sup>[1]</sup>
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

### Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition - Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information - Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

**Philips Semiconductors** 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088-3409 Telephone 800-234-7381

© Copyright Philips Electronics North America Corporation 2000 All rights reserved. Printed in U.S.A.

Date of release: 06-00

Document order number:

9397-750 07531

Let's make things better.



